

Product data sheet

Product profile

1.1 General description

PNP medium power transistor in a Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview**

| Type number[1] | Package | | Package |
|---------------------------------------|----------------|-------------|---------------|
| | NXP | JEITA | configuration |
| BCP69 | SOT223 | SC-73 | medium power |
| BCP69-16 | | | |
| BCP69-16/DG | | | |
| BCP69-16/IN | | | |
| BCP69-25 | | - A | |
| [1] /DG: halogen-free | | A TO SEE CA | |
| Features | | E am. | |
| High current | | CO | |
| ■ Three current g | ain selections | | |
| A A A A A A A A A A A A A A A A A A A | | | |

1.2 Features

- High current
- Three current gain selections
- 1.4 W total power dissipation
- Medium power SMD plastic package

1.3 Applications

- Linear voltage regulators
- High-side switches
- Supply line switches
- MOSFET drivers
- Audio preamplifier

1.4 Quick reference data

Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------|---------------------------|----------------------------------------|-----|-----|-----------|------|
| V_{CEO} | collector-emitter voltage | open base | - | - | -20 | V |
| I _C | collector current | | - | - | –1 | Α |
| I _{CM} | peak collector current | single pulse; t _n ≤ 1 ms | - | - | -2 | Α |



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Table 2. Quick reference data ... continued

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------|-------------------------|----------------------------------------------------|-----|-----|-----|------|
| h _{FE} | DC current gain | $V_{CE} = -1 \text{ V};$ $I_{C} = -500 \text{ mA}$ | | | | |
| | BCP69 | | 85 | - | 375 | |
| | BCP69-16 BCP69-16/DG | | 100 | - | 250 | |
| | BCP69-16/IN | | 140 | - | 230 | |
| | BCP69-25 | | 160 | - | 375 | |

2. Pinning information

Table 3. Pinning

| Table 3. | Filling | | |
|----------|-------------|--------------------|----------------|
| Pin | Description | Simplified outline | Graphic symbol |
| 1 | base | | |
| 2 | collector | 4 | 2, 4 |
| 3 | emitter | 4 15 /15 | 1— |
| 4 | collector | 1 2 3 | 3 |
| | | 4 36 - 10 | sym028 |

3. Ordering information

Table 4. Ordering information

| Type number[1] | Package | | |
|----------------|---------|------------------------------------------------|---------|
| | Name | Description | Version |
| BCP69 | SC-73 | plastic surface-mounted package with increased | SOT223 |
| BCP69-16 | | heatsink; 4 leads | |
| BCP69-16/DG | | | |
| BCP69-16/IN | | | |
| BCP69-25 | | | |

^{[1] /}DG: halogen-free

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4. Marking

Table 5. Marking codes

| Marking code |
|--------------|
| BCP69 |
| BCP69/16 |
| BCP69-16D |
| 69-16N |
| BCP69/25 |
| |

^{[1] /}DG: halogen-free

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

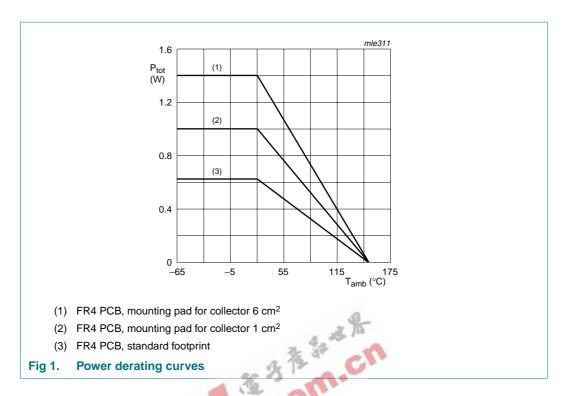
| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------------|----------------------------------------|--------------|------------|------|
| V_{CBO} | collector-base voltage | open emitter | | -32 | V |
| V_{CEO} | collector-emitter voltage | open base | 10 | -20 | V |
| V_{EBO} | emitter-base voltage | open collector | - | - 5 | V |
| I _C | collector current | -O' | - | -1 | Α |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | - | -2 | Α |
| I_{BM} | peak base current | $single pulse; \\ t_p \leq 1 \ ms$ | - | -200 | mA |
| P _{tot} | total power dissipation | $T_{amb} \le 25 ^{\circ}C$ | <u>[1]</u> - | 0.625 | W |
| | | | [2] _ | 1 | W |
| | | | [3] _ | 1.4 | W |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

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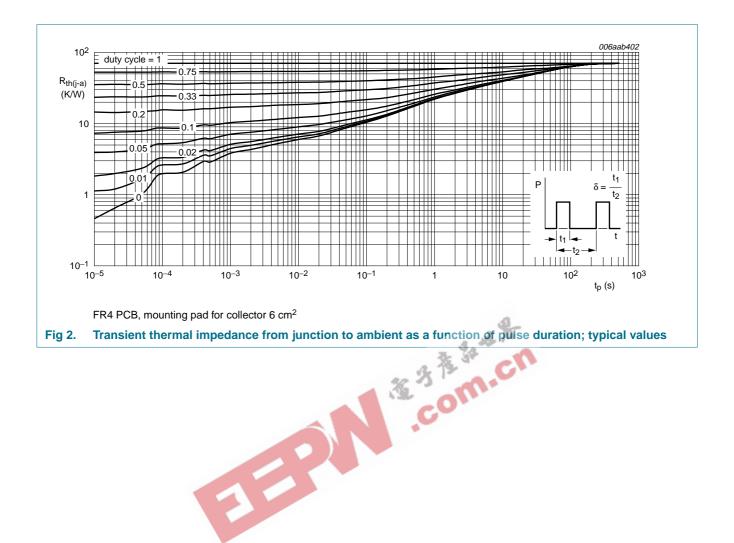
6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|--------------------------------------------------|-------------|--------------|-----|-----|------|
| R _{th(j-a)} | thermal resistance from junction | in free air | <u>[1]</u> - | - | 200 | K/W |
| | to ambient | [2 | [2] _ | - | 125 | K/W |
| | | | [3] _ | - | 89 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | - | - | 15 | K/W |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

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7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|--------------------------------------|------------------------------------------------------------------------------|-----|-----|------|------|
| I _{CBO} | collector-base cut-off | $V_{CB} = -25 \text{ V}; I_E = 0 \text{ A}$ | - | - | -100 | nA |
| | current | $V_{CB} = -25 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$ | - | - | -10 | μΑ |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$ | - | - | -100 | nA |
| h _{FE} | DC current gain | | | | | |
| | BCP69 | $V_{CE} = -10 \text{ V};$ $I_{C} = -5 \text{ mA}$ | 50 | - | - | |
| | | $V_{CE} = -1 \text{ V};$ $I_{C} = -500 \text{ mA}$ | 85 | - | 375 | |
| | | $V_{CE} = -1 V; I_{C} = -1 A$ | 60 | - | - | |
| | BCP69-16 BCP69-16/DG | $V_{CE} = -1 \text{ V};$ $I_{C} = -500 \text{ mA}$ $V_{CE} = -1 \text{ V};$ | 100 | - | 250 | |
| | BCP69-16/IN | $V_{CE} = -1 \text{ V};$ $I_{C} = -500 \text{ mA}$ | 140 | - | 230 | |
| | BCP69-25 | $V_{CE} = -1 \text{ V};$ $I_{C} = -500 \text{ mA}$ | 160 | - | 375 | |
| V_{CEsat} | collector-emitter saturation voltage | $I_{C} = -1 \text{ A};$ $I_{B} = -100 \text{ mA}$ | - | - | -500 | mV |
| V_{BE} | base-emitter voltage | $V_{CE} = -10 \text{ V};$ $I_{C} = -5 \text{ mA}$ | - | - | -700 | mV |
| | 1 | $V_{CE} = -1 \text{ V}; I_{C} = -1 \text{ A}$ | - | - | -1 | V |
| C _c | collector capacitance | $V_{CB} = -10 \text{ V};$ $I_E = i_e = 0 \text{ A};$ $f = 1 \text{ MHz}$ | - | 28 | - | pF |
| f _T | transition frequency | $V_{CE} = -5 \text{ V};$ $I_{C} = -50 \text{ mA};$ $f = 100 \text{ MHz}$ | 40 | 140 | - | MHz |

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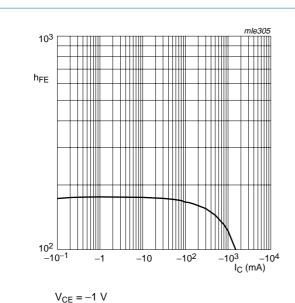


Fig 3. BCP69-16: DC current gain as a function of collector current; typical values

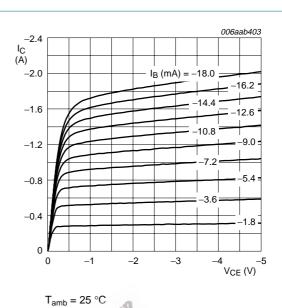


Fig 4. BCP69-16: Collector current as a function of collector-emitter voltage; typical values

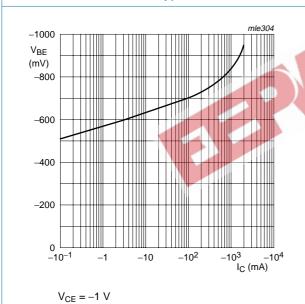
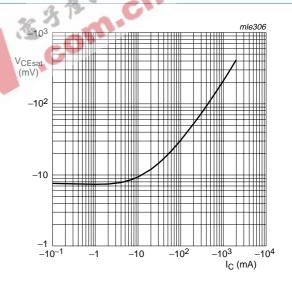


Fig 5. BCP69-16: Base-emitter voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B}=10$

Fig 6. BCP69-16: Collector-emitter saturation voltage as a function of collector current; typical values

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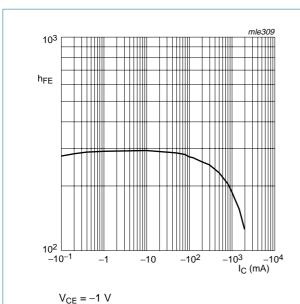


Fig 7. BCP69-25: DC current gain as a function of collector current; typical values

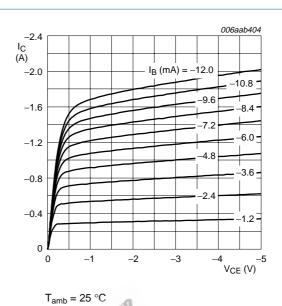


Fig 8. BCP69-25: Collector current as a function of collector-emitter voltage; typical values

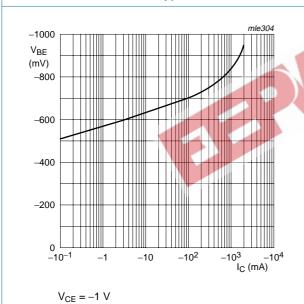
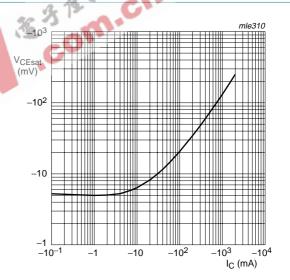


Fig 9. BCP69-25: Base-emitter voltage as a function of collector current; typical values



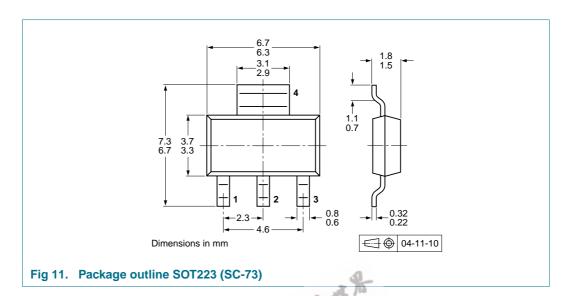
 $I_{\rm C}/I_{\rm B} = 10$

Fig 10. BCP69-25: Collector-emitter saturation voltage as a function of collector current; typical values

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8. Package outline



9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

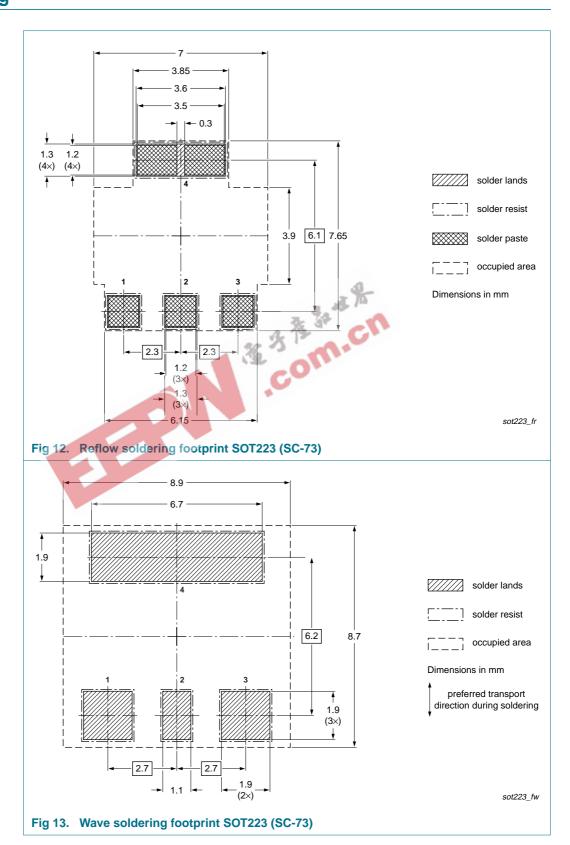
| Type number[2] | Package | Description | Packing | quantity |
|----------------|---------|---------------------------------|---------|----------|
| | | | 1000 | 4000 |
| BCP69 | SOT223 | 8 mm pitch, 12 mm tape and reel | -115 | -135 |
| BCP69-16 | | | | |
| BCP69-16/DG | | | | |
| BCP69-16/IN | | | | |
| BCP69-25 | | | | |

^[1] For further information and the availability of packing methods, see $\underline{\text{Section 13}}$.

^{[2] /}DG: halogen-free

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10. Soldering



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11. Revision history

Table 10. Revision history

| Release date | Data sheet status | Change notice | Supersedes | | |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|
| 20081202 | Product data sheet | - | BCP69_5 | | |
| | | redesigned to comply v | with the new identity | | |
| Legal texts have been adapted to the new company name where appropriate. | | | | | |
| • Table 1 "Pro | oduct overview": enhanced | | | | |
| • Table 4 "Or | dering information": enhance | ed | | | |
| • Figure 2, 4 | and 8: updated | | | | |
| Figure 11: superseded by minimized package outline drawing Section 9 "Packing information": added Section 10 "Soldering": enhanced | | | | | |
| | | | | | |
| | | | | | |
| • Section 12 | "Legal information": update | d | | | |
| 20031125 | Product specification | | BCP69_4 | | |
| 20021115 | Product specification | - 275 | BCP69_3 | | |
| 19990408 | Product specification | 25 M | BCP69_CNV_2 | | |
| | | com.c | | | |
| | 20081202 The format guidelines of Legal texts Table 1 "Pro Table 4 "Or Figure 2, 4 Figure 11: s Section 9 "I Section 10 Section 12 20031125 20021115 | Product data sheet The format of this data sheet has been guidelines of NXP Semiconductors. Legal texts have been adapted to the resulting information. Enhanced Table 1 "Product overview.": enhanced Table 4 "Ordering information.": enhanced Figure 2, 4 and 8: updated Figure 11: superseded by minimized personance information. Added the section 10 "Soldering.": enhanced Section 10 "Soldering.": enhanced Section 12 "Legal information.": update Product specification. | The format of this data sheet has been redesigned to comply of guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name who are the transfer of the new company name who are the transfer of the new company name who are the transfer of the new company name who are the transfer of the new company name who are the new company name ar | | |



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12. Legal information

12.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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Date of release: 2 December 2008 Document identifier: BCP69_6